

长春新产业光电技术有限公司

Changchun New Industries Optoelectronics Tech. Co., Ltd.

DATA SHEET

EO-XS-532/1~125µJ/1~5W

SPECIFICATIONS

LD PUMPED ALL-SOLID-STATE EOM Q-SWITCHED LASER AT 532 nm

All solid state EOM Q-switched laser at 532 nm has the features of high peak power, high repetition rate, and short pulse duration, which is widely used in marking, carving, measure, research and so on.



Wavelength (nm)	532±1	
Operating mode	Electro-optic Q-switched	
Average power (W)	1~5W (5W@40kHz)	
	Average power (W) = Single pulse energy (mJ) * Rep. rate (kHz)	
Single pulse energy (µJ)	1~125(125µJ @40kHz)	
Rep. rate (kHz)	1~100	
Pulse duration (ns)	~4@40kHz	
Peak power (kW)	1~36 (36kW@40kHz)	
Ave power stability (over 4 hours)	<3%	
Warm-up time (minutes)	<10	
Beam divergence, full angle (mrad)	<3	
Beam diameter at the aperture (1/e2,mm)	~1.5	
M ² factor	<1.5	
Beam height from base plate (mm)	101	
Cooled method	Air cooled	
Operating temperature (°C)	10~35	
Power supply (220/110VAC)	PSU-AOM (3U)	
Expected lifetime (hours)	10000	
Warranty period	1 year	









